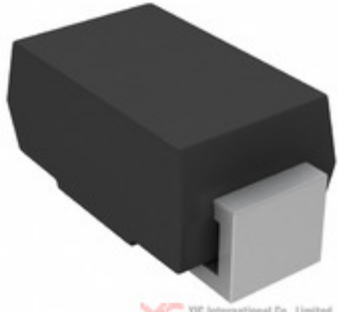

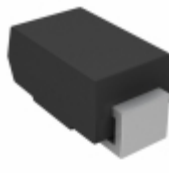
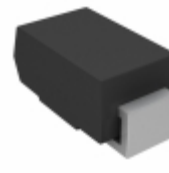
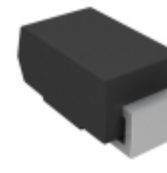
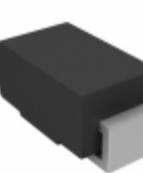
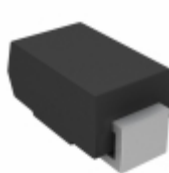


	<h2>S1MHE3/61T</h2>
	<p><b>Hersteller-Teilenummer:</b> S1MHE3/61T</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> DIODE GEN PURP 1KV 1A DO214AC</p> <p><b>Datenblätter:</b> <a href="#">1.S1MHE3/61T.pdf</a> <a href="#">2.S1MHE3/61T.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 87920 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	S1MHE3/61T
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	DIODE GEN PURP 1KV 1A DO214AC
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Dioden-Gleichrichter-</a>
Teilstatus	87920 pcs Stock
detaillierte Beschreibung	Diode Standard 1000V 1A Surface Mount DO-214AC
Serie	Automotive, AEC-Q100
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	5µA @ 1000V
Spannung - Sperr (Vr) (max)	1000V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	-
Verpackung	Tape & Reel (TR)
Basisteilenummer	S1M
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

S1MHE3/61T ist neu im Original, Suche S1MHE3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1MHE3/61T Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage S1MHE3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>
 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 1KV 1A DO214AC</p>	 <p><b>S1MG</b> Original S1MG Original</p>

### heiße Teile

Mehr

5STP04X5200	AT89LP52-20JU	BD3571FP-E2	BT131W-800	BUL903EDFP
CD74HC4316PWR	CRCW251230R0JNTG-30R	CY26121Z1-21	DS1230Y-100+	GRM2166P1H7R0DZ01D
IXFH8N65	LA76070N	LM22677TJE-ADJ	LM2936HVMA-5.0	MAX706TESA
MIC5249-2.85BMM	MM1021XS	RB068LAM150	RSX101VA-30FSTR	S1M-13-F
S1M-E3/5AT	S1M-E3/5AT	S1M-E3/61T	S1M-E3/61T	S1M-M3/61T
S1M-M3/61T	S1M0V043B1J8100	S1M8656A01-F0T0	S1M8662A01-Z070	S1M8691X01-J070
S1M8732X01-Y070	S1M8837X01	S1M8837X01-N0T0	S1MB-13-F	S1MHE3/61T
S1MHE3_A/H	S1MHE3_A/H	S1MHE3_A/I	S1MHE3_A/I	S1MSP1-F
S1MSWF-7	S1MSWFQ-7	SCG2001944	STGB20NB41LZT4	TEA5767HN/V3+118
UNR921TJ08	XC9110C301MR	XP-B60-05	ZMM5263B-7-F	ZR404005F25TA

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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